

SGM4564 4-Bit Bidirectional Voltage-Level Translator with Auto Direction Sensing

GENERAL DESCRIPTION

This 4-bit non-inverting voltage-level translator uses two separate configurable power-supply rails. The A ports are designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2V to 5.5V. The B ports are designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65V to 5.5V. This allows for universal low-voltage bidirectional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5V voltage nodes. V_{CCA} should not exceed V_{CCB} .

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state. To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull-down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SGM4564 is designed so that the OE input circuit is supplied by V_{CCA} .

This device is fully specified for partial-power-down applications using I_{OFF} . The I_{OFF} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SGM4564 is available in Green SOIC-14 and UTQFN-1.8×1.8-12L packages. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES

- 1.2V to 5.5V on A Ports and 1.65V to 5.5V on B Ports (V_{CCA} ≤ V_{CCB})
- V_{CC} Isolation: If Either V_{CC} is at GND,
 All Outputs are in the High-Impedance State
- OE Input Circuit Referenced to V_{CCA}
- Low Power Consumption
- Push-Pull Output
- I_{OFF}: Supports Partial-Power-Down Mode Operation
- -40°C to +85°C Operating Temperature Range
- Available in Green SOIC-14 and UTQFN-1.8×1.8-12L Packages

APPLICATIONS

Smart-Phone
Portable Equipments
UART
GPIO

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM4564	UTQFN-1.8×1.8-12L	-40℃ to +85℃	SGM4564YUQN12G/TR	4564 XXXX	Tape and Reel, 3000
3314304	SOIC-14	-40℃ to +85℃	SGM4564YS14G/TR	SGM4564YS14 XXXXX	Tape and Reel, 2500

NOTE: XXXX = Date Code, XXXXX = Date Code and Vendor Code.

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

ADSOLUTE MAXIMUM KATI	NGS
V _{CCA} , Supply Voltage Range	0.3V to 6V
V _{CCB} , Supply Voltage Range	0.3V to 6V
V _I , Input Voltage Range	
A Ports	0.3V to 6V
B Ports	0.3V to 6V
V _O , Voltage Range Applied to Any Impedance or Power-Off State	Output in the High-
A Ports	0.3V to 6V
B Ports	
V_{O} , Voltage Range Applied to Any Outp	
State (1)	
A Ports	
B Ports	-0.3V to V_{CCB} + 0.3V
I_{IK} , Input Clamp Current $(V_I < 0)$	50mA
I_{OK} , Output Clamp Current ($V_O < 0$)	25mA
Continuous Current through V_{CCA} , V_{CCB} ,	or GND
	±100mA
Junction Temperature	150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10sec)	260°C
ESD Susceptibility	
HBM	4000V
MM	300V

NOTE: 1. The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

OVERSTRESS CAUTION

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.

RECOMMENDED OPERATING CONDITIONS (2, 3)

Supply Voltage Range	
V _{CCA}	1.2V to 5.5V
V _{CCB}	1.65V to 5.5V
High-Level Input Voltage, VIH	
Data Inputs	$V_{\rm CCI} \times 0.85^{(4)} \text{to} V_{\rm CCI}$
OE Input	$V_{CCA} \times 0.85$ to 5.5V
Low-Level Input Voltage, V _{IL}	
Data Inputs	0V to $V_{CCI} \times 0.2^{(4)}$
OE Input	0V to V _{CCA} × 0.2
Voltage Range Applied to Any Output in	the High-Impedance
or Power-Off State, V _O	
A Ports	0V to 5.5V
B Ports	0V to 5.5V
Input Transition Rise or Fall Rate, $\Delta t/\Delta V$	
A Port Inputs	40ns/V (MAX)
B Port Inputs	40ns/V (MAX)
Operating Temperature Range	40°C to +85°C

NOTES:

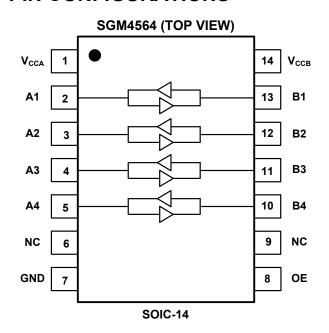
- 2. The A and B sides of an unused data I/O pair must be held in the same state, i.e., both at V_{CCI} or both at GND.
- 3. V_{CCA} must be less than or equal to V_{CCB} and must not exceed 5.5V.
- 4. V_{CCI} is the supply voltage associated with the input ports.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SGM4564 (TOP VIEW)

PIN CONFIGURATIONS



B2 В4 12 11 10 9 8 V_{CCB} ΟE 7 2 GND \textbf{V}_{CCA} 3 4 5 6 Α1 **A2** А3 Α4

UTQFN-1.8×1.8-12L

PIN DESCRIPTION

F	PIN			
SOIC-14	UTQFN- 1.8×1.8-12L	NAME	FUNCTION	
1	2	V_{CCA}	A Port Supply Voltage. $1.2V \le V_{CCA} \le 5.5V$ and $V_{CCA} \le V_{CCB}$.	
2	3	A1	Input/Output 1. Referenced to V _{CCA} .	
3	4	A2	Input/Output 2. Referenced to V _{CCA} .	
4	5	A3	Input/Output 3. Referenced to V _{CCA} .	
5	6	A4	Input/Output 4. Referenced to V _{CCA} .	
6	_	NC	No Connection. Not internally connected.	
7	7	GND	Ground.	
8	8	OE	3-State Output-Mode Enable. Pull OE low to place all outputs in 3-state mode. Referenced to V_{CCA} .	
9	_	NC	No Connection. Not internally connected.	
10	9	B4	Input/Output 4. Referenced to V _{CCB} .	
11	10	В3	Input/Output 3. Referenced to V _{CCB} .	
12	11	B2	Input/Output 2. Referenced to V _{CCB} .	
13	12	B1	Input/Output 1. Referenced to V _{CCB} .	
14	1	V _{CCB}	B Port Supply Voltage. 1.65V ≤ V _{CCB} ≤ 5.5V.	

ELECTRICAL CHARACTERISTICS (1)

(Full = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.)

PARAMETER		CONDITIONS		TEMP	MIN	TYP	MAX	UNITS	
A Dawla High Lavel Output	t) (alta = a () ()	1 - 204	V _{CCA} = 1.2V	+25°C		1.05			
A Ports High Level Output	t voltage (voha)	Ι _{ΟΗ} = -20μΑ	V _{CCA} = 1.4V to 5.5V	Full	V _{CCA} - 0.3]	
A Ports Low Level Output	\\altaga (\\)	V _{CCA} = 1.2V		+25°C		0.1			
A Ports Low Level Output	voltage (V _{OLA})	I _{OL} = 20μA	V _{CCA} = 1.4V to 5.5V	Full			0.3]	
B Ports High Level Output	t Voltage (V _{OHB})	I _{OH} = -20μA	V _{CCB} = 1.65V to 5.5V	Full	V _{CCB} - 0.3]	
B Ports Low Level Output	Voltage (V _{OLB})	I _{OL} = 20μA	V _{CCB} = 1.65V to 5.5V	Full			0.3		
Input Leakage Current	OE	OE = V _{CCA} or GND,		+25°C			±1		
(I_i)	OL	$V_{CCA} = 1.2V \text{ to } 5.5^{\circ}$	$V, V_{CCB} = 1.65V \text{ to } 5.5V$	Full			±1.5		
	A Ports	V_1 or $V_0 = 0V$ to 5.5		+25°C			±0.5		
Power Off Leakage Current (I _{OFF})	ATORS	$V_{CCA} = 0V, V_{CCB} =$	0V to 5.5V	Full			±1	μΑ	
	B Ports	V_1 or $V_0 = 0V$ to 5.5		+25°C			±0.5]	
	DT OILS	$V_{CCA} = 0V \text{ to } 5.5V,$	V _{CCB} = 0V	Full			±1		
3-State Output Leakage			+25°C			±0.5			
(loz)	7. 6. 2.1 6.16	V _{CCB} = 1.65V to 5.5V		Full			±1		
			$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		0.1			
Outcoant Supply Current	. //	$V_1 = V_{CCI}$ or GND,	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$				12		
Quiescent Supply Current	L (ICCA)	$I_O = 0$, OE = V_{CCA}	V _{CCA} = 5.5V, V _{CCB} = 0V	Full			12	μΑ	
			$V_{CCA} = 0V,$ $V_{CCB} = 5.5V$				-1		
			$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C Full		1		- - μΑ	
Quiescent Supply Current	t (loca)	$V_1 = V_{CCI}$ or GND, $I_0 = 0$,	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$				10		
Quiscom Cuppi, Cuiton	(1008)	OE = V _{CCA}	V _{CCA} = 5.5V, V _{CCB} = 0V				-1		
			$V_{CCA} = 0V,$ $V_{CCB} = 5.5V$				9		
Quiescent Supply Current	t (loca + loca)	$V_1 = V_{CCI}$ or GND, $I_0 = 0$,	$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		1		μΑ	
autosom cappi, camoni	(ICCA ICCB)	OE = V _{CCA}	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	Full	Full		19	,	
Quiescent Supply Current	t (locza)	$V_1 = V_{CCI}$ or GND, $I_0 = 0$,	$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		0.1		μA	
Quiescent Supply Current (ICCZA)		OE = GND	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	Full			12	μΛ	
Quiescent Supply Current (I _{CCZB})		$V_i = V_{CCi}$ or GND, $I_0 = 0$,	$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		0.1		μΔ	
Quiescent Supply Cultern	(ICCZB)	0E = GND	V_{CCA} = 1.4V to 5.5V, V_{CCB} = 1.65V to 5.5V	Full			9	μA	
OE Input Capacitance (C _I)	V _{CCA} = 1.2V to 5.5	V, V _{CCB} = 1.65V to 5.5V	+25°C		5.2		pF	
Input/Output	A Ports	V = 1 2\/ to 5 5	// // = 1.65\/ to 5.5\/	+25°C		4.4		nE	
Capacitance (C _{IO})	B Ports	V_{CCA} = 1.2V to 5.5V, V_{CCB} = 1.65V to 5.5V		+25°C		4.4		- pF	

NOTE:

1. V_{CCI} is the supply voltage associated with the input ports.

TIMING REQUIREMENTS

		V _{CCB} = 1.8V	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS
		TYP	TYP	TYP	TYP	UNITS
(T _A = +25°C, V _{CCA} = 1.	2V, unless other	wise noted.)	•	•		
Data Rate		20	20	20	20	Mbps
Pulse Duration (t _w)	Data Inputs	50	50	50	50	ns
(T _A = +25°C, V _{CCA} = 1.	5V, unless other	wise noted.)	•	•		
Data Rate		40	40	40	40	Mbps
Pulse Duration (t _W)	Data Inputs	25	25	25	25	ns
(T _A = +25°C, V _{CCA} = 1.	8V, unless other	wise noted.)				
Data Rate		60	60	60	60	Mbps
Pulse Duration (t _w)	Data Inputs	17	17	17	17	ns
(T _A = +25°C, V _{CCA} = 2.	5V, unless other	wise noted.)				
Data Rate			100	100	100	Mbps
Pulse Duration (tw)	Data Inputs		10	10	10	ns
(T _A = +25°C, V _{CCA} = 3.	3V, unless other	wise noted.)				
Data Rate				100	100	Mbps
Pulse Duration (t _w)	Data Inputs			10	10	ns
(T _A = +25°C, V _{CCA} = 5°	V, unless otherwi	se noted.)				
Data Rate					100	Mbps
Pulse Duration (t _w)	Data Inputs				10	ns

SWITCHING CHARACTERISTICS

 $(T_A = +25^{\circ}C, V_{CCA} = 1.2V, unless otherwise noted.)$

DAD	AMETER	FROM	то	V _{CCB} = 1.8V	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS
PAR	AMETER	(INPUT)	(OUTPUT)	TYP	TYP	TYP	TYP	UNITS
	t _{PLH}	Α	В	23.8	21.2	20.4	20.6	
+	t _{PHL}	A	Ь	30.0	28.4	29.5	31.4	ns
t _{PD}	t _{PLH}	В	А	31.1	27.6	27.3	28.8	115
	t _{PHL}	В	A	22.0	19.8	19.3	18.2	
	t _{PZH}		Α	70.1	68.8	67.6	64.5	
	t _{PZL}	OE	A	58.9	55.8	56.3	56.1	200
t _{EN}	t _{PZH}	OE .	В	44.2	40.7	41.0	42.8	ns
	t _{PZL}		В	69.7	66.4	67.5	67.5	
	t _{PHZ}		۸	1050	1070	1030	1040	
	t _{PLZ}	OE	Α	480	480	490	470]
t _{DIS}	t _{PHZ}	OE .	В	1080	1090	1080	1100	ns
	t _{PLZ}		Ь	510	560	570	560	
	t _{rA}	A Ports F	Rise Time	18.0	17.1	16.8	14.7	ns
	t _{fA}	A Ports	Fall Time	7.2	6.1	5.2	2.5	ns
			Rise Time	3.6	2.3	1.9	1.5	ns
	t_{fB}	B Ports	Fall Time	2.4	1.9	1.8	1.5	ns
1	t _{SK(O)}	Channel-to-C	Channel Skew	1	1	1	1	ns
Da	ta Rate			20	20	20	20	Mbps

SWITCHING CHARACTERISTICS

 $(T_A = +25^{\circ}C, V_{CCA} = 1.5V, unless otherwise noted.)$

DAD	AMETER	FROM	то	V _{CCB} = 1.8V	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	LINITO	
PAR	AMETER	(INPUT)	(OUTPUT)	TYP	TYP	TYP	V _{CCB} = 5V TYP 11.7 11.3 11.5 8.3 30.9 26.2 21.1 31.1 1010 500 1090 550 3.9 2.6 1.7 1.6	UNITS	
	t _{PLH}	Α	В	15.9	13.6	12.6	11.7		
t _{PD}	t _{PHL}	1 ^	Ь	14.6	12.1	11.5	11.3	no	
L PD	t _{PLH}	В	А	14.0	13.5	11.4	11.5	ns	
	t _{PHL}	В	A	12.0	10.6	9.7	8.3		
	t _{PZH}		۸	31.2	31.4	31.7	30.9		
	t _{PZL}	OE	Α	32.4	27.9	26.8	26.2	no	
t _{EN}	t _{PZH}	OE	OE	В	28.3	23.1	21.7	21.1	ns
	t _{PZL}		Ь	34.1	29.9	30.4	31.1		
	t _{PHZ}		OE A	1000	1030	1020	1010	- ns	
	t _{PLZ}	05		500	490	500	500		
t _{DIS}	t _{PHZ}	OE		1080	1070	1070	1090		
	t _{PLZ}		В	510	550	550	550		
	t _{rA}	A Ports F	Rise Time	7.2	5.9	5.3	3.9	ns	
	t _{fA}	A Ports I	Fall Time	2.5	2.8	3.2	2.6	ns	
t_{rB}		B Ports F	Rise Time	3.9	2.5	2.0	1.7	ns	
	t_{fB}	B Ports I	Fall Time	3.2	1.9	1.7	1.6	ns	
1	SK(O)	Channel-to-C	hannel Skew	0.5	0.5	0.5	0.5	ns	
Da	ta Rate			40	40	40	40	Mbps	

SWITCHING CHARACTERISTICS

 $(T_A = +25^{\circ}C, V_{CCA} = 1.8V, unless otherwise noted.)$

DAD	AMETER	FROM	то	V _{CCB} = 1.8V	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS				
PARA	AWIETEK	(INPUT)	(OUTPUT)	TYP	TYP	TYP	TYP 9.1 7.8 7.9 5.5 22.0 19.4 16.3 21.1 1060 510 1080 540 2.8 2.5 1.5 1.5 0.5	UNITS				
	t _{PLH}	А	В	11.6	11.5	10.1	9.1					
	t _{PHL}	A	Ь	10.6	8.3	8.1	7.8	no				
t _{PD}	t _{PLH}	В	А	9.1	10.5	8.4	7.9	ns				
	t _{PHL}	Ь	A	9.1	7.2	TYP 10.1 8.1 8.4 7.5 21.8 19.8 17.5 19.8 1080 520 1060 540 2.9 2.2 1.8 2.1 0.5	5.5					
	t _{PZH}		^	21.9	21.6	21.8	22.0					
	t _{P7I}	OE	Α	25.9	21.1	19.8	19.4					
t _{EN}	t _{PZH}	OE .	В	29.4	18.6	17.5	16.3	ns				
	t _{PZL}		В	25.0	21.6	19.8	21.1					
	t _{PHZ}		A	1080	1050	1080	1060					
	t _{PLZ}	OE	OE	OF	OE	OE _	A	520	500	520	510	no
t _{DIS}	t _{PHZ}	OE	В	1040	1070	1060	1080	ns				
	t _{PLZ}		В	520	540	540	540					
	t _{rA}	A Ports F	Rise Time	3.0	3.9	2.9	2.8	ns				
	t _{fA}	A Ports	Fall Time	2.2	2.4	2.2	2.5	ns				
	t _{rB}	B Ports F	Rise Time	2.9	2.2	1.8	1.5	ns				
	t_fB	B Ports	Fall Time	2.1	2.2	2.1	1.5	ns				
1	SK(O)	Channel-to-C	Channel Skew	0.5	0.5	0.5	0.5	ns				
Dat	ta Rate			60	60	60	60	Mbps				

SWITCHING CHARACTERISTICS

(T_A = +25°C, V_{CCA} = 2.5V, unless otherwise noted.)

DAD	AMETER	FROM	то	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS
PAR	AWEIEK	(INPUT)	(OUTPUT)	TYP	TYP	TYP	UNITS
	t _{PLH}	А	В	9.6	7.6	5.2	
	t _{PHL}		Ь	6.7	5.3	5.1	
t_{PD}	t _{PLH}	В	А	7.8	6.3	4.5	ns
	t _{PHL}	В	A	5.0	TYP TYP 7.6 5.2 5.3 5.1 6.3 4.5 6.0 3.2 14.5 14.3 13.8 13.6 15.3 14.8 14.7 15.7 1070 1050 550 530 1070 1080 550 540 2.5 2.7 2.0 2.1 1.9 2.1 1.8 1.5 0.5 0.5		
	t _{PZH}		۸	14.4	14.5	14.3	
4	t _{PZL}	OE	Α	15.9	13.8	13.6	
t_{EN}	t _{PZH}	OE	В	17.5	15.3	14.8	ns
	t _{PZL}		Ь	15.4	14.7	15.7	
	t _{PHZ}		A	1050	1070	1050	
4	t _{PLZ}	05	A	550	550	530	
t _{DIS}	t _{PHZ}	OE	В	1050	1070	1080	ns
	t _{PLZ}		Ь	550	550	540	
	t _{rA}	A Ports F	Rise Time	2.7	2.5	2.7	ns
	t _{fA}	A Ports I	Fall Time	2.9	2.0	2.1	ns
	t _{rB}	B Ports F	Rise Time	2.4	1.9	2.1	ns
	t _{fB}	B Ports I	Fall Time	2.6	1.8	1.5	ns
	t _{SK(O)}	Channel-to-C	Channel Skew	0.5	0.5	0.5	ns
Da	ta Rate			100	100	100	Mbps

SWITCHING CHARACTERISTICS

 $(T_A = +25^{\circ}C, V_{CCA} = 3.3V, unless otherwise noted.)$

DAD	AMETER	FROM	то	V _{CCB} = 3.3V	$V_{CCB} = 5V$	UNITS
PAR	AWEIER	(INPUT)	(OUTPUT)	TYP	TYP	UNIIS
	t _{PLH}	^	В	5.4	3.6	
	t _{PHL}	Α Α	Б	4.3	3.3	
t _{PD}	t _{PLH}	В	۸	4.8	4.0	ns
	t _{PHL}]	A	4.6	2.8	
	t _{PZH}		٨	12.5	12.0	
	t _{PZL}	05	Α	13.5	11.4	T
$t_{\sf EN}$	N t _{PZH} OE] OE	B 15.9 12.7	12.8	ns	
	t _{PZL}			12.7	13.5	
	t _{PHZ}			1080	1080	
	t _{PLZ}	OE	А	540	540	T
t _{DIS}	t _{PHZ}			1060	1080	ns
	t _{PLZ}		В	550	540	
	t _{rA}	A Ports	Rise Time	1.5	1.5	ns
	t _{fA}	A Ports	Fall Time	1.6	1.6	ns
	t _{rB}	B Ports	Rise Time	1.5	1.0	ns
	t _{fB}	B Ports	Fall Time	1.5	1.0	ns
1	t _{SK(O)}	Channel-to-0	Channel Skew	0.5	0.5	ns
	ta Rate			100	100	Mbps

SWITCHING CHARACTERISTICS

($T_A = +25$ °C, $V_{CCA} = 5V$, unless otherwise noted.)

DADA	METED	FROM	то	V _{CCB} = 5V	LINUTO	
PARA	AMETER	(INPUT)	(OUTPUT)	TYP	UNITS	
	t _{PLH}	А	В	3.4		
	t _{PHL}		В	2.9	no	
t _{PD}	$t_{\sf PLH}$	В	Α	3.3	ns	
	t _{PHL}	Ь	A	2.6		
	$t_{\sf PZH}$		Α	11.7		
	t _{PZL}	OE -	A	12.3	no	
$t_{\sf EN}$	t _{PZH}		OE	В	13.8	ns
	t _{PZL}		В	13.3		
	t _{PHZ}		A	1070		
	t_{PLZ}	OF	A	530		
t _{DIS}	t _{PHZ}	OE	В	1080	ns	
	t _{PLZ}		В	540		
	t_{rA}	A Ports F	Rise Time	1.2	ns	
	t _{fA}	A Ports I	all Time	1.3	ns	
	t _{rB}	B Ports F	Rise Time	1.1	ns	
	t _{fB}	B Ports I	all Time	1.3	ns	
t	SK(O)	Channel-to-C	hannel Skew	0.5	ns	
Dat	a Rate			100	Mbps	

OPERATING CHARACTERISTICS

 $(T_A = 25^{\circ}C, unless otherwise noted.)$

PARAMETER							V _{CCA}					
			1.2V	1.2V	1.5V	1.8V	2.5V	2.5V	3.3V	3.3V	5V	
		TEST CONDITIONS	V _{CCB}									
			5V	1.8V	1.8V	1.8V	2.5V	5V	3.3V	5V	5V	
			TYP	TYP	TYP	TYP	TYP	TYP	TYP	TYP	TYP	
	A Port Inputs, B Port Outputs	0 - 0	75	71	37	10	11	12	12	13	14	,
C _{PDA}	B Port Inputs, A Port Outputs	$C_L = 0,$ f = 10MHz, $t_r = t_f = 1ns,$ $OE = V_{CCA}$ (Outputs Enabled)	6	6	6	6	6	6	6	6	6	
	A Port Inputs, B Port Outputs		7	6	6	6	6	6	6	6	6	pF
СРОВ	B Port Inputs, A Port Outputs		18	105	11	10	10	12	12	13	14	
C _{PDA}	A Port Inputs, B Port Outputs	$C_1 = 0$	0.005	0.005	0.004	0.003	0.003	0.003	0.002	0.002	0.002	
OPDA	B Port Inputs, A Port Outputs	f = 10MHz, $t_r = t_f = 1ns$,	0.011	0.007	0.018	0.010	0.011	0.004	0.006	0.004	0.006	pF
C_PDB	A Port Inputs, B Port Outputs	OE = GND (Outputs Disabled)	0.001	0.003	0.003	0.003	0.003	0.002	0.002	0.002	0.002	pi
OPDB	B Port Inputs, A Port Outputs		0.003	0.004	0.010	0.003	0.007	0.002	0.003	0.002	0.001	

APPLICATION INFORMATION

Applications

The SGM4564 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another.

Architecture

The SGM4564 architecture (see Figure 1) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a DC state, the output drivers of the SGM4564 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing the opposite direction.

The output one-shots detect rising or falling edges on the A or B ports. During a rising edge, the one-shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one-shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition. The typical output impedance during output transition is 70Ω at $V_{\rm CCO}$ = 1.2V to 1.8V, 50Ω at $V_{\rm CCO}$ = 1.8V to 3.3V, and 40Ω at $V_{\rm CCO}$ = 3.3V to 5V.

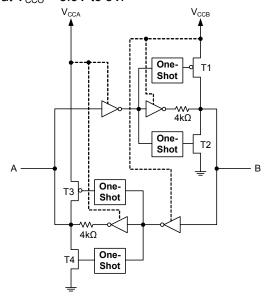
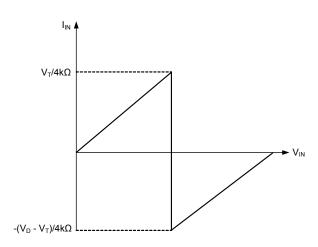


Figure 1. Architecture of SGM4564 I/O Cell

Input Driver Requirements

Typical I_{IN} vs. V_{IN} characteristics of the SGM4564 are shown in Figure 2. For proper operation, the device driving the data I/Os of the SGM4564 must have drive strength of at least $\pm 2\text{mA}$.



A. V_T is the input threshold voltage of the SGM4564 (typically $V_{CCI}/2$). B. V_D is the supply voltage of the external driver.

Figure 2. Typical I_{IN} vs. V_{IN} Curve

Power Up

During operation, ensure that $V_{CCA} \le V_{CCB}$ at all times. During power-up sequencing, $V_{CCA} \ge V_{CCB}$ does not damage the device, so any power supply can be ramped up first. The SGM4564 has circuitry that disables all output ports when either V_{CC} is switched off $(V_{CCA/B} = 0V)$.

Enable and Disable

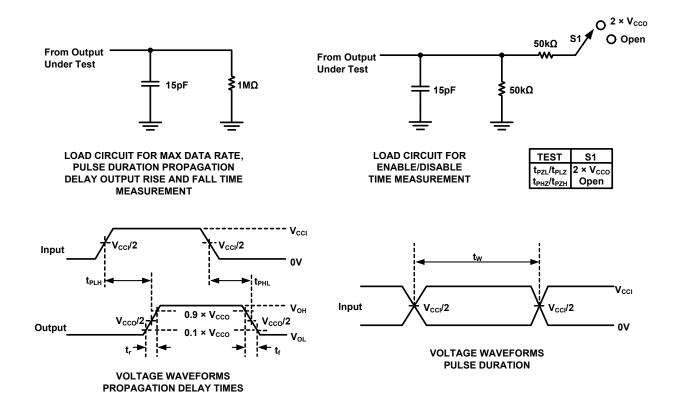
The SGM4564 has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time (t_{DIS}) indicates the delay between when OE goes low and when the outputs are actually disabled (Hi-Z). The enable time (t_{EN}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

Pull-Up or Pull-Down Resistors on I/O Lines

The SGM4564 is designed to drive capacitive loads of up to 70pF. The output drivers of the SGM4564 have low DC drive strength. If pull-up or pull-down resistors are connected externally to the data I/Os, their values must be kept higher than $50k\Omega$ to ensure that they do not contend with the output drivers of the SGM4564.

For the same reason, the SGM4564 should not be used in applications such as I^2C or 1-wire where an open-drain driver is connected on the bidirectional data I/O.

PARAMETER MEASUREMENT INFORMATION



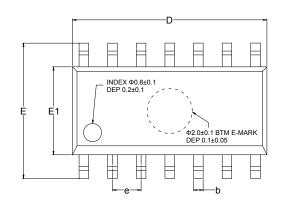
NOTES:

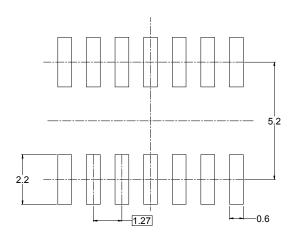
- 1. C_L includes probe and jig capacitance.
- 2. All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, $Z_0 = 50\Omega$, $dv/dt \geq 1V/ns$.
- 3. The outputs are measured one at a time, with one transition per measurement.
- 4. t_{PLH} and t_{PHL} are the same as t_{PD} .
- 5. V_{CCI} is the V_{CC} associated with the input ports.
- 6. V_{CCO} is the V_{CC} associated with the output ports.
- 7. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuits and Voltage Waveforms

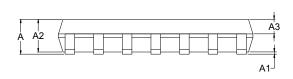
PACKAGE OUTLINE DIMENSIONS

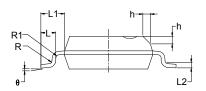
SOIC-14





RECOMMENDED LAND PATTERN (Unit: mm)

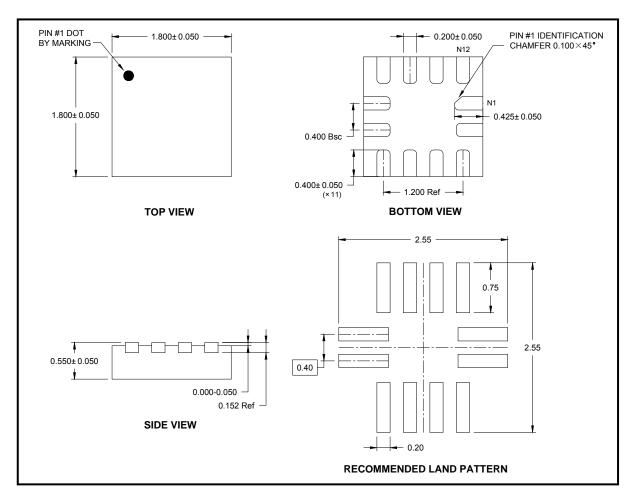




Symbol		Dimensions n Millimeter		Dimensions In Inches					
•	MIN	MOD	MAX	MIN	MOD	MAX			
Α	1.35		1.75	0.053		0.069			
A1	0.10		0.25	0.004		0.010			
A2	1.25		1.65	0.049		0.065			
А3	0.55		0.75	0.022		0.030			
b	0.36		0.49	0.014		0.019			
D	8.53		8.73	0.336		0.344			
E	5.80		6.20	0.228		0.244			
E1	3.80		4.00	0.150		0.157			
е		1.27 BSC			0.050 BSC				
L	0.45		0.80	0.018		0.032			
L1	1.04 REF			0.040 REF					
L2	0.25 BSC			0.01 BSC					
R	0.07			0.003					
R1	0.07			0.003					
h	0.30		0.50	0.012		0.020			
θ	0°		8°	0°		8°			

PACKAGE OUTLINE DIMENSIONS

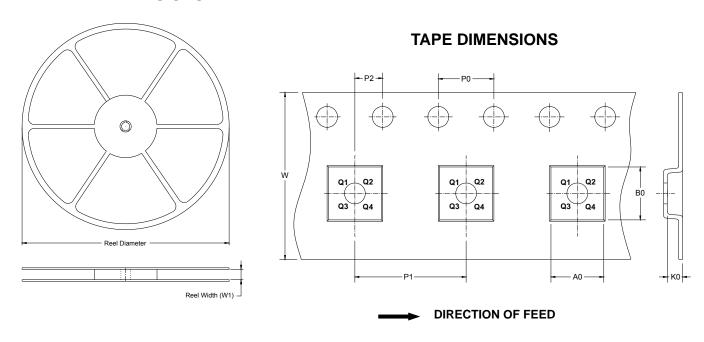
UTQFN-1.8×1.8-12L



NOTE: All linear dimensions are in millimeters.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

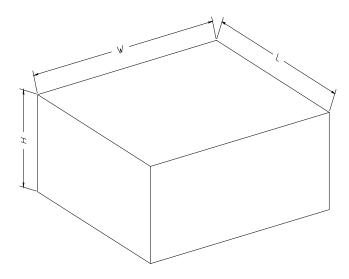


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-14	13"	16.4	6.6	9.3	2.1	4.0	8.0	2.0	16.0	Q1
UTQFN-1.8×1.8-12L	7"	9.0	2.1	2.1	0.8	4.0	4.0	2.0	8.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5